

## TO-92 Plastic-Encapsulate Transistors

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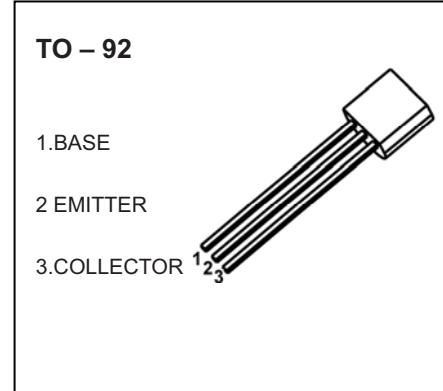
### **MPSH10 TRANSISTOR (NPN)**

#### **FEATURES**

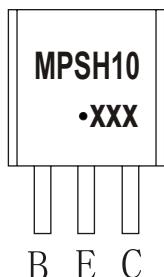
- General Purpose Amplifier

#### **APPLICATIONS**

- In Low Noise UHF/VHF Amplifiers
- In Low Frequency Drift, High Output UHF Oscillators

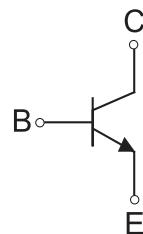


#### **MARKING**



MPSH10=Device code  
 Solid dot=Green molding compound device,  
 if none,the normal device  
 XXX=Code

#### **Equivalent Circuit**



#### **ORDERING INFORMATION**

Part Number	Package	Packing Method	Pack Quantity
MPSH10	TO-92	Bulk	1000pcs/Bag
MPSH10-TA	TO-92	Tape	2000pcs/Box

#### **MAXIMUM RATINGS (T<sub>a</sub>=25°C unless otherwise noted)**

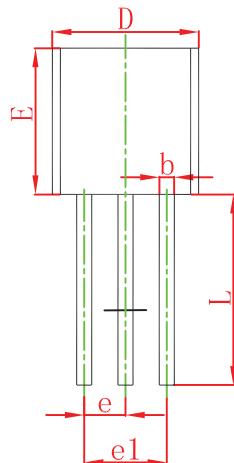
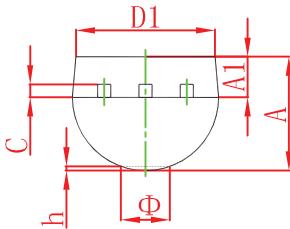
Symbol	Parameter	Value	Unit
V <sub>CBO</sub>	Collector-Base Voltage	30	V
V <sub>CEO</sub>	Collector-Emitter Voltage	25	V
V <sub>EBO</sub>	Emitter-Base Voltage	3	V
I <sub>c</sub>	Collector Current -Continuous	40	mA
P <sub>D</sub>	Collector Power Dissipation	350	mW
R <sub>θJA</sub>	Thermal Resistance from Junction to Ambient	357	°C /W
T <sub>j</sub>	Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature	-55~+150	°C

## ELECTRICAL CHARACTERISTICS

T<sub>a</sub>=25 °C unless otherwise specified

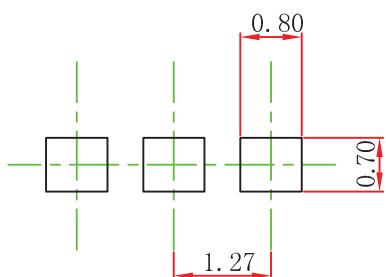
Parameter	Symbol	Test conditions	Min	Typ	Max	Unit
Collector-base breakdown voltage	V <sub>(BR)CBO</sub>	I <sub>C</sub> = 0.1mA, I <sub>E</sub> =0	30			V
Collector-emitter breakdown voltage	V <sub>(BR)CEO</sub>	I <sub>C</sub> =1mA, I <sub>B</sub> =0	25			V
Emitter-base breakdown voltage	V <sub>(BR)EBO</sub>	I <sub>E</sub> =0.01mA, I <sub>C</sub> =0	3			V
Collector cut-off current	I <sub>CBO</sub>	V <sub>CB</sub> =25V, I <sub>E</sub> =0			0.1	µA
Emitter cut-off current	I <sub>EBO</sub>	V <sub>EB</sub> =2V, I <sub>C</sub> =0			0.1	µA
DC current gain	h <sub>FE(1)</sub>	V <sub>CE</sub> =10V, I <sub>C</sub> =4mA	60			
Collector-emitter saturation voltage	V <sub>CE(sat)</sub>	I <sub>C</sub> =4mA, I <sub>B</sub> =0.4mA			0.5	V
Base-emitter voltage	V <sub>BE</sub>	I <sub>C</sub> =4mA, V <sub>CE</sub> =10V			0.95	V
Transition frequency	f <sub>T</sub>	V <sub>CE</sub> =10V, I <sub>C</sub> =4mA, f=100MHz	650			MHz
Collector output capacitance	C <sub>cb</sub>	V <sub>CB</sub> =10V, I <sub>E</sub> =0, f=1MHz			0.7	pF

## TO-92 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min	Max	Min	Max
A	3.300	3.700	0.130	0.146
A1	1.100	1.400	0.043	0.055
b	0.380	0.550	0.015	0.022
c	0.360	0.510	0.014	0.020
D	4.300	4.700	0.169	0.185
D1	3.430		0.135	
E	4.300	4.700	0.169	0.185
e	1.270 TYP		0.050 TYP	
e1	2.440	2.640	0.096	0.104
L	14.100	14.500	0.555	0.571
Φ		1.600		0.063
h	0.000	0.380	0.000	0.015

## TO-92 Suggested Pad Layout



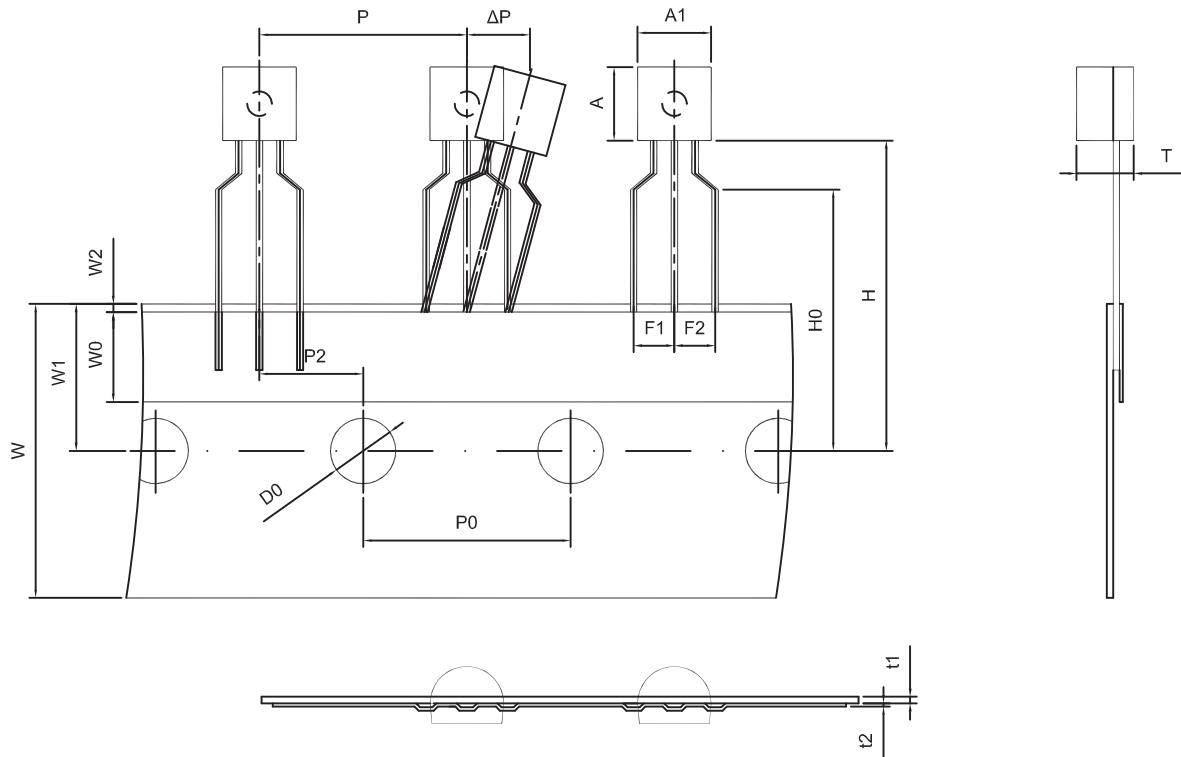
### Note:

1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.05$ mm.
3. The pad layout is for reference purposes only.

### NOTICE

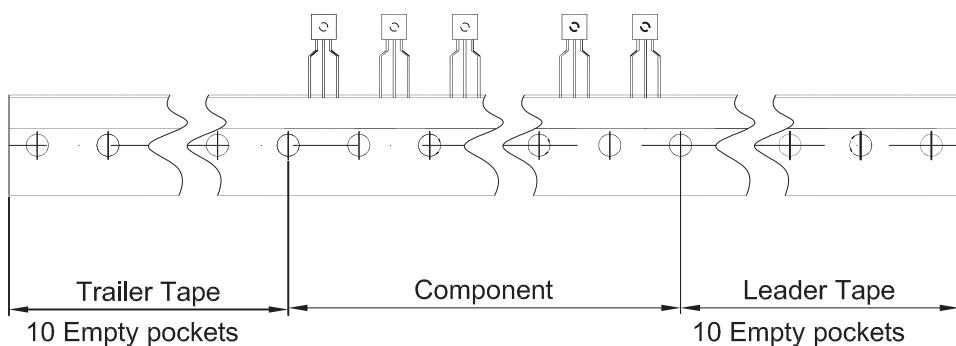
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## TO-92 PACKAGE TAPEING DIMENSION



Dimensions are in millimeter

A1	A	T	P	P0	P2	F1	F2	W
4.5	4.5	3.5	12.7	12.7	6.35	2.5	2.5	18.0
W0	W1	W2	H	H0	D0	t1	t2	ΔP
6.0	9.0	1.0 MAX.	19.0	16.0	4.0	0.4	0.2	0



Package	Box	Box Size(mm)	Carton	Carton Size(mm)
TO-92	2000 pcs	333×162×43	20,000 pcs	350×340×250